

Si photodiode

S8193

Detector for X-ray monitors

Features

Applications

- High sensitivity, high reliability photodiode with ceramic scintillator
- High X-ray sensitivity: 1.8 times that of CWO
- Less afterglow than CsI: <0.1%/3 ms, <0.01%/30 ms</p>
- Unlike CsI, has no deliquescence

X-ray analysis, X-ray detection

Absolute maximum ratings (Ta=25 °C)

Parameter	Symbol	Value	Unit
Reverse voltage	VR max	5	V
Operating temperature	Topr	-10 to +60	°C
Storage temperature	Tstg	-20 to +70	°C

Electrical and optical characteristics (without scintillator, Ta=25°C)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Spectral response range	λ		-	190 to 1000	-	nm
Peak sensitivity wavelength	λр			720	-	nm
Photosensitivity	S	λ=500 nm	-	0.26	-	A/W
		λ=λp	-	0.5	-	A/W
Dark current	ID	VR=10 mV	-	2	50	pА
Terminal capacitance	Ct	VR=0 V, f=10 kHz	-	950	-	pF

X-ray sensitivity (reference value, tube current: 1.0 mA, aluminum filter: t=6 mm, distance=830 mm)

X-ray tube voltage	Тур.	Unit
120 keV	30	nA

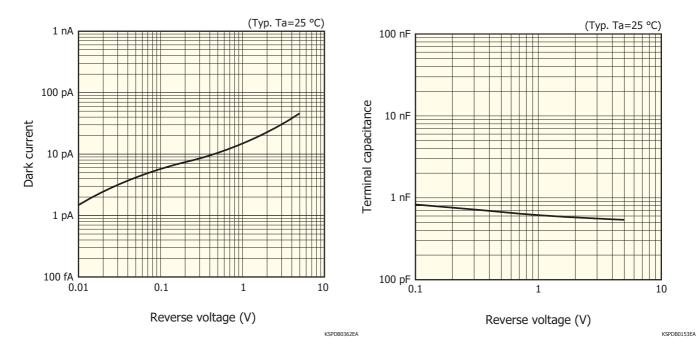
Note: Depends on equipment and measurement conditions

1

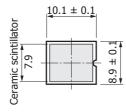
S8193

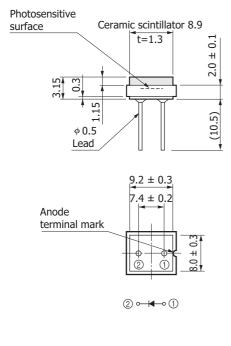
Dark current vs. reverse voltage

- Terminal capacitance vs. reverse voltage



Dimensional outline (unit: mm)





HAMAMATSU

KSPDB0129EB

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- Disclaimer
- Metal, ceramic, plastic package products

Information described in this material is current as of September 2016.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.



www.hamamatsu.com

HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Higashi-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81) 53-434-3311, Fax: (81) 53-434-5184

1126-1 IChino-Cho, HigaShi-Ku, Hamamatsu City, 435-8558 Japan, Ielephone: (81) 53-434-3311, FaX: (81) 53-434-5184 U.S.A.: Hamamatsu Corporation: 360 Foothill Road, Bridgewater, N.J. 08807, U.S.A., Telephone: (1) 908-231-0960, Fax: (1) 908-231-218 Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49) 8152-375-0, Fax: (49) 8152-265-8 France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: 33-(1) 69 53 71 00, Fax: 33-(1) 69 53 71 10 United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire AL7 1BW, United Kingdom, Telephone: (44) 1707-294888, Fax: (44) 1707-325777 North Europe: Hamamatsu Photonics Italia S.r.L.: Strada della Moia, 1 int. 6, 20020 Arese (Milano), Italy, Telephone: (39) 02-93581733, Fax: (39) 02-93581741 China: Hamamatsu Photonics (China) Co., Ltd.: B1201, Jiaming Center, No.27 Dongsanhuan Beilu, Chaoyang District, Beijing 100020, China, Telephone: (86) 10-6586-6006, Fax: (86) 10-6586-2866

Cat. No. KSPD1042E03 Sep. 2016 DN